Low-Voltage CMOS 16-Bit Latching Transceiver

With 5V-Tolerant Inputs and Outputs (3-State, Non-Inverting)

MC74LCX16543A

LCX

LOW–VOLTAGE CMOS 16–BIT LATCHING TRANSCEIVER

The MC74LCX16543A is a high performance, non–inverting 16–bit latching transceiver operating from a 2.7 to 3.6V supply. The device is byte controlled. Each byte has separate control inputs which can be tied together for full 16–bit operation. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A V_I specification of 5.5V allows MC74LCX16543A inputs to be safely driven from 5V devices. The MC74LCX16543A is suitable for memory address driving and all TTL level bus oriented transceiver applications.

For data flow from A to B with the $\overline{EAB}$ LOW, the A–to–B Output Enable (OEAB) must be LOW in order to enable data to the B bus, as indicated in the Function Table. With EAB LOW, a LOW signal on the A–to–B Latch Enable (LEAB) input makes the A–to–B latches transparent; a subsequent LOW–to–HIGH transition of the LEAB signal will latch the A latches, and the outputs no longer change with the A inputs. With EAB and OEAB both LOW, the 3–State B output buffers are active and reflect the data present at the output of the A latches. Control of data flow from B to A is symmetric to that above, but uses the EBA, LEBA, and OEBA inputs.

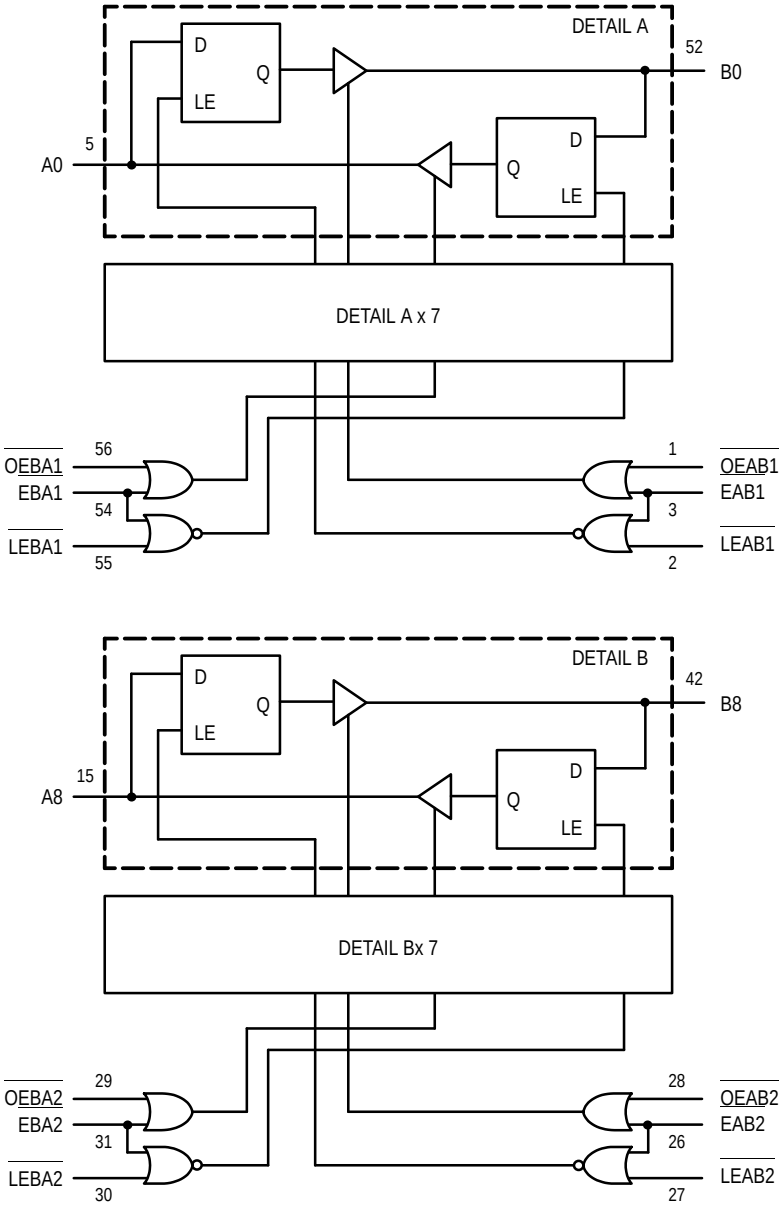
DT SUFFIX
56–LEAD PLASTIC TSSOP PACKAGE
CASE 1202–01

- Designed for 2.7 to 3.6V V_{CC} Operation
- 5.2ns Maximum t_{pd}
- 5V Tolerant — Interface Capability With 5V TTL Logic
- Supports Live Insertion and Withdrawal
- I_{OFF} Specification Guarantees High Impedance When V_{CC} = 0V
- LVTTL Compatible
- LVCMOS Compatible
- 24mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current in All Three Logic States (20μA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500mA
- ESD Performance: Human Body Model >2000V; Machine Model >200V

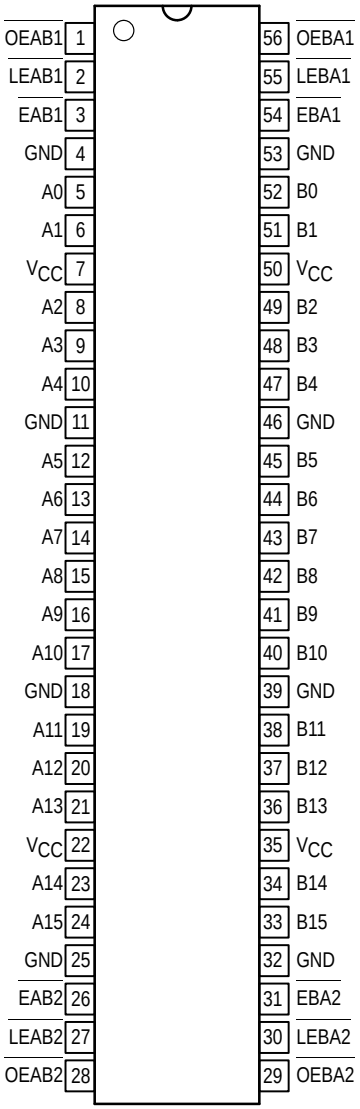
PIN NAMES

Pins	Function
$\overline{OExn}$	Output Enable Inputs
Exxn	Enable Inputs
LExxn	Latch Enable Inputs
A0–A15	3–State Inputs/Outputs
B0–B15	3–State Inputs/Outputs

LOGIC DIAGRAM



Pinout: 56-Lead TSSOP
(Top View)



FUNCTION TABLE

Inputs						Data Ports		Operating Mode
OEABn	**OEBAn**	**EABn**	**EBAn**	**LEABn**	**LEBAn**	**An**	**Bn**	
H	H					**Input**	**Input**	
		X	X	X	X	X	X	Disable Outputs
		L	L	L	L	X	X	Transparent Data; Outputs Disabled
				H	H	l h	l h	Latch and Outputs Disabled
L	H					**Input**	**Output**	
		H	X*	L	X	l h	Z Z	Load and B Outputs Disabled
				H	X	X	Z	Hold; B Outputs Disabled
		L	X*	L	X	L H	L H	Transparent A to B
				H	X	l h	L H	Latch and Display B Outputs
H	L					**Output**	**Input**	
		X*	H	X	L	Z Z	l h	Load and A Outputs Disabled
				X	H	Z	X	Hold; A Outputs DIsabled
		X*	L	X	L	L H	L H	Transparent B to A
				X	H	L H	l h	Latch and Display A Outputs

H = High Voltage Level; h = High Voltage Level One Setup Time Prior to the Latch Enable or Enable Low–to–High Transition; L = Low Voltage Level; l = Low Voltage Level One Setup Time Prior to the Latch Enable or Enable Low–to–High Transition; X = Don't Care; * = The latches are not internally gated with the Output Enables. Therefore, data at the A or B ports may enter the latches at any time, provided that the LExx and Exx pins are set accordingly. For I_{CC} reasons, Do Not Float Inputs.

ABSOLUTE MAXIMUM RATINGS*

Symbol	Parameter	Value	Condition	Unit
V_{CC}	DC Supply Voltage	–0.5 to +7.0		V
V_I	DC Input Voltage	$–0.5 \le V_I \le +7.0$		V
V_O	DC Output Voltage	$–0.5 \le V_O \le +7.0$	Output in 3–State	V
		$–0.5 \le V_O \le V_{CC} + 0.5$	Note 1.	V
I_{IK}	DC Input Diode Current	–50	V_I < GND	mA
I_{OK}	DC Output Diode Current	–50	V_O < GND	mA
		+50	$V_O > V_{CC}$	mA
I_O	DC Output Source/Sink Current	±50		mA
I_{CC}	DC Supply Current Per Supply Pin	±100		mA
I_{GND}	DC Ground Current Per Ground Pin	±100		mA
T_{STG}	Storage Temperature Range	–65 to +150		°C

* Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute–maximum–rated conditions is not implied.

1. Output in HIGH or LOW State. I_O absolute maximum rating must be observed.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Typ	Max	Unit
V_{CC}	Supply Voltage	Operating Data Retention Only	2.0 1.5	3.3 3.3	3.6 3.6	V
V_I	Input Voltage		0		5.5	V
V_O	Output Voltage	(HIGH or LOW State) (3–State)	0 0		V_{CC} 5.5	V
I_{OH}	HIGH Level Output Current, V_{CC} = 3.0V – 3.6V				–24	mA
I_{OL}	LOW Level Output Current, V_{CC} = 3.0V – 3.6V				24	mA
I_{OH}	HIGH Level Output Current, V_{CC} = 2.7V – 3.0V				–12	mA
I_{OL}	LOW Level Output Current, V_{CC} = 2.7V – 3.0V				12	mA
T_A	Operating Free–Air Temperature		–40		+85	°C
$\Delta t/\Delta V$	Input Transition Rise or Fall Rate, V_{IN} from 0.8V to 2.0V, V_{CC} = 3.0V		0		10	ns/V

DC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic	Condition	T_A = –40°C to +85°C		Unit
			Min	Max	
V_{IH}	HIGH Level Input Voltage (Note 2.)	2.7V ≤ V_{CC} ≤ 3.6V	2.0		V
V_{IL}	LOW Level Input Voltage (Note 2.)	2.7V ≤ V_{CC} ≤ 3.6V		0.8	V
V_{OH}	HIGH Level Output Voltage	2.7V ≤ V_{CC} ≤ 3.6V; I_{OH} = –100μA	V_{CC} – 0.2		V
		V_{CC} = 2.7V; I_{OH} = –12mA	2.2		
		V_{CC} = 3.0V; I_{OH} = –18mA	2.4		
		V_{CC} = 3.0V; I_{OH} = –24mA	2.2		
V_{OL}	LOW Level Output Voltage	2.7V ≤ V_{CC} ≤ 3.6V; I_{OL} = 100μA		0.2	V
		V_{CC} = 2.7V; I_{OL}= 12mA		0.4	
		V_{CC} = 3.0V; I_{OL} = 16mA		0.4	
		V_{CC} = 3.0V; I_{OL} = 24mA		0.55	
I_I	Input Leakage Current	2.7V ≤ V_{CC} ≤ 3.6V; 0V ≤ V_I ≤ 5.5V		±5.0	μA
I_{OZ}	3–State Output Current	2.7 ≤ V_{CC} ≤ 3.6V; 0V ≤ V_O ≤ 5.5V; V_I = V_{IH} or V_{IL}		±5.0	μA
I_{OFF}	Power–Off Leakage Current	V_{CC} = 0V; V_I or V_O = 5.5V		10	μA
I_{CC}	Quiescent Supply Current	2.7 ≤ V_{CC} ≤ 3.6V; V_I = GND or V_{CC}		20	μA
		2.7 ≤ V_{CC} ≤ 3.6V; 3.6 ≤ V_I or V_O ≤ 5.5V		±20	μA
ΔI_{CC}	Increase in I_{CC} per Input	2.7 ≤ V_{CC} ≤ 3.6V; V_{IH} = V_{CC} – 0.6V		500	μA

2. These values of V_I are used to test DC electrical characteristics only.

AC CHARACTERISTICS ($t_R = t_F = 2.5ns$; $C_L = 50pF$; $R_L = 500\Omega$)

Symbol	Parameter	Waveform	Limits				Unit
			$T_A = -40°C$ to $+85°C$				
			$V_{CC} = 3.0V$ to $3.6V$		$V_{CC} = 2.7V$		
			Min	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay An to Bn or Bn to An	1	1.5 1.5	5.4 5.4	1.5 1.5	6.0 6.0	ns
t_{PLH} t_{PHL}	Propagation Delay LEBAn to An or LEABn to Bn	4	1.5 1.5	7.0 7.0	1.5 1.5	8.2 8.2	ns
t_{PZH} t_{PZL}	Output Enable Time OEBAn to An or OEABn to Bn	2	1.5 1.5	6.5 6.5	1.5 1.5	7.0 7.0	ns
t_{PHZ} t_{PLZ}	Output Disable Time OEBAn to An or OEABn to Bn	2	1.5 1.5	6.5 6.5	1.5 1.5	7.0 7.0	ns
t_{PZH} t_{PZL}	Output Enable Time EBAn to An or EABn to Bn	2	1.5 1.5	6.5 6.5	1.5 1.5	7.0 7.0	ns
t_{PHZ} t_{PLZ}	Output Disable Time EBAn to An or EABn to Bn	2	1.5 1.5	6.5 6.5	1.5 1.5	7.0 7.0	ns
t_s	Setup Time, HIGH to LOW Data to LExxn	4	2.5		2.5		ns
t_h	Hold Time, HIGH to LOW Data to LExxn	4	1.5		1.5		ns
t_s	Setup Time, HIGH to LOW Data to Exxn	4	2.5		2.5		ns
t_h	Hold Time, HIGH to LOW Data to Exxn	4	1.5		1.5		ns
t_w	Latch Enable or Enable Pulse Width, LOW	4	3.0		3.0		ns
t_{OSHL} t_{OSLH}	Output–to–Output Skew (Note 3.)			1.0 1.0			ns

3. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH–to–LOW (t_{OSHL}) or LOW–to–HIGH (t_{OSLH}); parameter guaranteed by design.

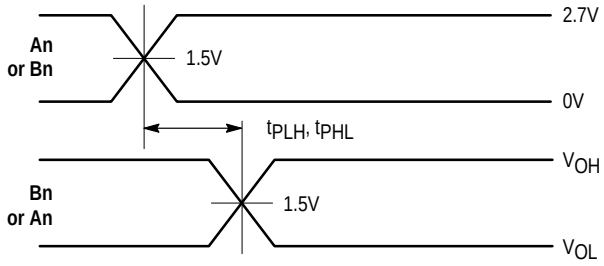
DYNAMIC SWITCHING CHARACTERISTICS

Symbol	Characteristic	Condition	$T_A = +25°C$			Unit
			Min	Typ	Max	
V_{OLP}	Dynamic LOW Peak Voltage (Note 4.)	$V_{CC} = 3.3V$, $C_L = 50pF$, $V_{IH} = 3.3V$, $V_{IL} = 0V$		0.8		V
V_{OLV}	Dynamic LOW Valley Voltage (Note 4.)	$V_{CC} = 3.3V$, $C_L = 50pF$, $V_{IH} = 3.3V$, $V_{IL} = 0V$		0.8		V

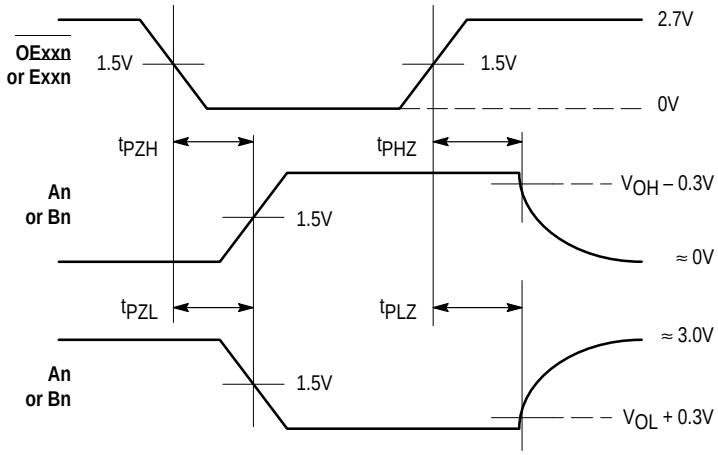
4. Number of outputs defined as “n”. Measured with “n–1” outputs switching from HIGH–to–LOW or LOW–to–HIGH. The remaining output is measured in the LOW state.

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C_{IN}	Input Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	7	pF
$C_{I/O}$	Input/Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	10MHz, $V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	20	pF

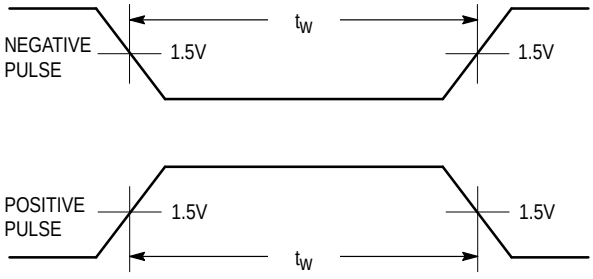


WAVEFORM 1 – A/B to B/A PROPAGATION DELAYS
$t_R = t_F$ = 2.5ns, 10% to 90%; f = 1MHz; t_W = 500ns

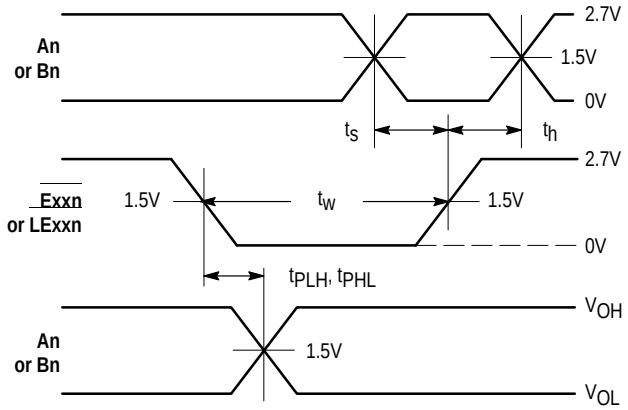


WAVEFORM 2 – $\overline{OE}$xx/$\overline{E}$xx to A or B OUTPUT ENABLE AND DISABLE TIMES
$t_R = t_F$ = 2.5ns, 10% to 90%; f = 1MHz; t_W = 500ns

Figure 1. AC Waveforms

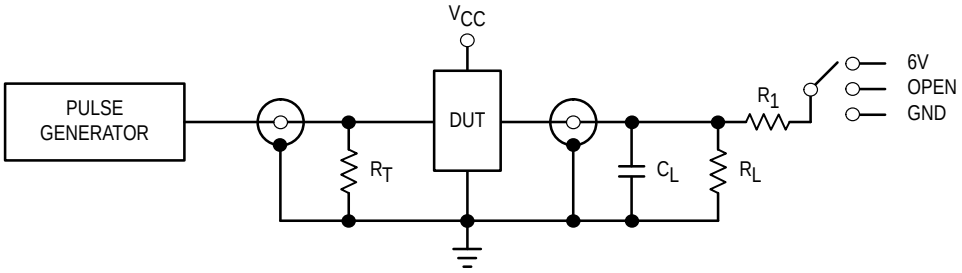


WAVEFORM 3 – INPUT PULSE DEFINITION
$t_R = t_F$ = 2.5ns, 10% to 90% of 0V to 2.7V



WAVEFORM 4 – Enable to A or B PROPAGATION DELAYS, Enable MINIMUM PULSE WIDTH, A or B to Enable SETUP AND HOLD TIMES
$t_R = t_F$ = 2.5ns, 10% to 90%; f = 1MHz; t_W = 500ns except when noted

Figure 2. AC Waveforms (continued)



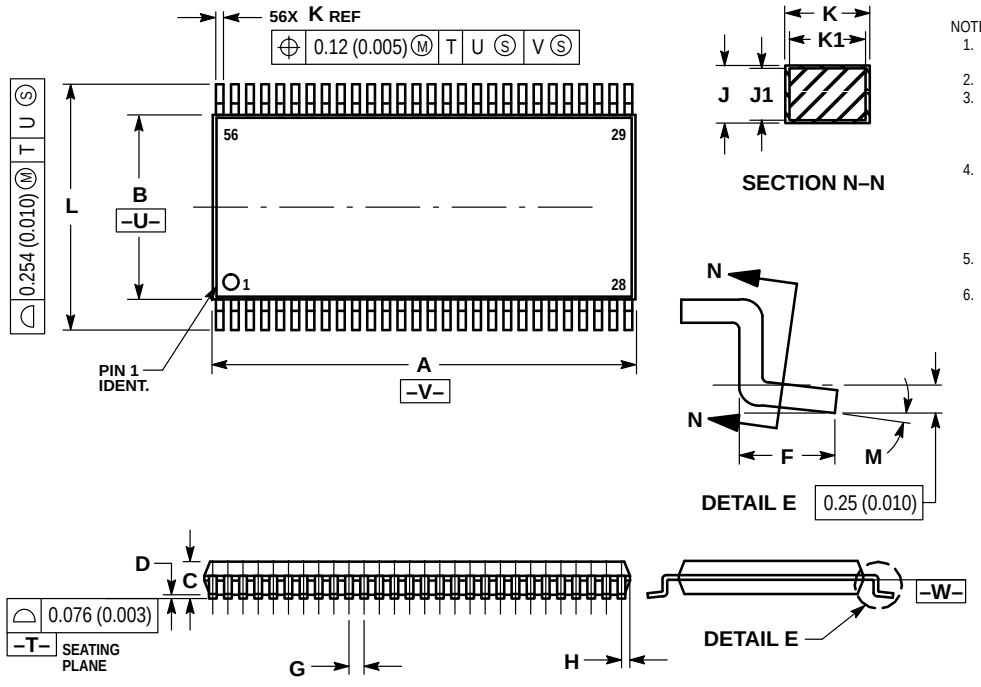
TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V
Open Collector/Drain t_{PLH} and t_{PHL}	6V
t_{PZH}, t_{PHZ}	GND

C_L = 50pF or equivalent (Includes jig and probe capacitance)
$R_L = R_1$ = 500Ω or equivalent
$R_T = Z_{OUT}$ of pulse generator (typically 50Ω)

Figure 3. Test Circuit

OUTLINE DIMENSIONS

DT SUFFIX
PLASTIC TSSOP PACKAGE
CASE 1202–01
ISSUE A



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
6. DIMENSIONS A AND B ARE TO BE DETERMINED AT DATUM PLANE –W–.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	13.90	14.10	0.547	0.555
B	6.00	6.20	0.236	0.244
C	—	1.10	—	0.043
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.50 BSC		0.0197 BSC	
H	0.12	—	0.005	—
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.17	0.27	0.007	0.011
K1	0.17	0.23	0.007	0.009
L	7.95	8.25	0.313	0.325
M	0°	8°	0°	8°

How to reach us:
USA / EUROPE / Locations Not Listed: Motorola Literature Distribution; P.O. Box 5405; Denver, Colorado 80217. 303–675–2140 or 1–800–441–2447

Mfax™: RMFAX0@email.sps.mot.com – TOUCHTONE 602–244–6609
INTERNET: http://Design–NET.com

JAPAN: Nippon Motorola Ltd.; Tatsumi–SPD–JLDC, 6F Seibu–Butsuryu–Center, 3–14–2 Tatsumi Koto–Ku, Tokyo 135, Japan. 81–3–3521–8315

ASIA / PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298